Introduction to topological aspects in condensed matter physics

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Ten-fold classification of topological insulators and superconductors

1st lecture:

- Topological band theory
- Topological insulators in 1D (polyacetylene)
- Topological insulators in 2D (IQHE, QSHE)

2nd lecture:

- Topological insulators w/ TRS in 2D & 3D (Z₂ invariant)
- BdG theory for superconductors
- Topological superconductors in 1D and 2D
- Majorana bound states

3rd lecture:

- Topological superconductors in 2D and 3D w/ TRS
- Periodic table of topological insulators and superconductors

4th lecture:

- Topological crystalline insulators
- Gapless topological materials

Review articles:

- M.Z. Hasan and C.L. Kane, Rev. Mod. Phys. 82, 3045 (2010)
- X.L. Qi and S.C. Zhang, Rev. Mod. Phys. 83, 1057 (2011)
- S. Ryu, A. P. Schnyder, A. Furusaki, A. Ludwig, New J. Phys. 12, 065010 (2010)
- C. Beenakker, Annual Review of Cond. Mat. Phys. 4, 113 (2013)
- J. Alicea, Rep. Prog. Phys. 75, 076501 (2012)
- Y. Ando, J. Phys. Soc. Jpn. 82, 102001 (2013)

Books:

- Shun-Qing Shen, "Topological insulators", Springer Series in Solid-State Sciences, Volume 174 (2012)
- B. Andrei Bernevig, "Topological Insulators and Topological Superconductors", Princeton University Press (2013)
- Mikio Nakahara, "Geometry, Topology and Physics", Taylor & Francis (2003)
- A. Bohm, A. Mostafazadeh, H. Koizumi, Q. Niu, J. Zwanziger, "The geometric phase in quantum systems", Springer (2003)
- M. Franz and L. Molenkamp, "Topological Insulators", Contemporary Concepts of Condensed Matter Science, Elsevier (2013)

1st lecture: Topological band theory

- 1. Introduction
 - What is topology?
 - Topological band theory
- 2. Topological insulators in 1D
 - Berry phase
 - Simple example: Two-level system
 - Polyacetylene (Su-Schrieffer-Heeger model)
 - Domain wall states
- 3. Topological insulators in 2D
 - Integer quantum Hall effect
 - Bulk boundary correspondence
 - Chern insulator on square lattice

What is topology?

The study of geometric properties that are insensitive to smooth deformations For example, consider two-dimensional surfaces in three-dimensional space

Closed surface is characterized by its genus g = # holes



g is an integer topological invariant

Gauss-Bonnet Theorem

Genus can be expressed in terms of an integral of the Gauss curvature over the surface

$$\int_{S} \kappa \, dA = 4\pi (1-g)^{\mathbf{A}}$$

topological invariant

In condensed matter physics:

Topology of insulating materials, topology of band structures

Band theory of solids and topology

Bloch's theorem: consider electron wavefunction in periodic crystal potential

Electron wavefunction in crystal $|\psi_n\rangle = e^{i\mathbf{k}\cdot\mathbf{r}} |u_n(\mathbf{k})\rangle$ Bloch wavefunction has periodicity of potential

Bloch Hamiltonian $H(\mathbf{k}) = e^{-i\mathbf{k}\mathbf{r}}He^{+i\mathbf{k}\mathbf{r}}$ $H(\mathbf{k}) |u_n(\mathbf{k})\rangle = E_n(\mathbf{k}) |u_n(\mathbf{k})\rangle$ $\mathbf{k} \in \text{Brillouin Zone}$ $\frac{\pi/a}{-\pi/a}$ π/a \mathbf{k}_x =

Band structure defines a mapping:

Brillouin zone $\longmapsto H(\mathbf{k})$ Hamiltonians with energy gap

Topological equivalence:

Band structures are equivalent if they can be continuously deformed into one another without closing the energy gap



p_crystal momentum

Band theory and topology

Berry phase:

Phase ambiguity of wavefuction $|u(\mathbf{k})\rangle \rightarrow e^{i\phi_{\mathbf{k}}} |u(\mathbf{k})\rangle$

U(1) fiber bundle: to each k attach fiber $\{g | u(k) \rangle \mid g \in U(1)\}$

define Berry connection: (like EM vector potential)

$$\mathcal{A} = \langle u_{\boldsymbol{k}} | - i \nabla_k | u_{\boldsymbol{k}} \rangle$$

under gauge transformation:

$$|u(\mathbf{k})\rangle \to e^{i\phi_{\mathbf{k}}} |u(\mathbf{k})\rangle \implies \mathcal{A} \to \mathcal{A} + \nabla_{\mathbf{k}}\phi_{\mathbf{k}}$$

Berry phase: (gauge invariant quantity)

change in phase on a closed loop

Berry curvature tensor: (gauge independent)

For 3D: $\mathcal{F} = \nabla_{k} \times \mathcal{A}$ $\mathcal{F}_{\mu\nu} = \epsilon_{\mu\nu\xi} \mathcal{F}_{\mu\nu}$

$$\pi = \left| u(\mathbf{k}) \right\rangle$$

$$\mathcal{F}_{\mu\nu}(\mathbf{k}) = \frac{\partial}{\partial k_{\mu}} \mathcal{A}_{\nu}(\mathbf{k}) - \frac{\partial}{\partial k_{\nu}} \mathcal{A}_{\mu}(\mathbf{k})$$

$$\epsilon_{\mu\nu\xi} \mathcal{F}_{\xi} \qquad \qquad \mathbf{Stokes:} \quad \gamma_{C} = \int_{S} \mathcal{F} \cdot d\mathbf{k}$$

 $\gamma_C = \oint \mathcal{A} \cdot d\mathbf{k}$

Topological invariants of band structures:

Topological property of insulating material given by Chern number (or winding number):

$$n = \frac{i}{2\pi} \sum_{\substack{\text{filled}\\\text{states}}} \int \mathcal{F} d^2 k$$

Berry phase for two-level system

Two-level Hamiltonian: $H(\mathbf{k}) = \mathbf{d}(\mathbf{k}) \cdot \boldsymbol{\sigma} = \begin{pmatrix} d_z & d_x - id_y \\ d_x + id_y & -d_z \end{pmatrix}$

param. by spherical coord.: $d(k) = |d|(\sin \theta \cos \phi, \sin \theta \sin \phi, \cos \theta)$ two eigenvectors with energies $E_{\pm} = \pm |d|$ (north pole gauge)

$$\left|u_{\boldsymbol{k}}^{-}\right\rangle = \begin{pmatrix}\sin(\theta/2)e^{-i\phi}\\-\cos(\theta/2)\end{pmatrix}$$
 $\left|u_{\boldsymbol{k}}^{+}\right\rangle = \begin{pmatrix}\cos(\theta/2)e^{-i\phi}\\\sin(\theta/2)\end{pmatrix}$

Berry vector potential: (gauge dependent)

$$A_{\theta} = i \left\langle u_{\boldsymbol{k}}^{-} \middle| \partial_{\theta} \middle| u_{\boldsymbol{k}}^{-} \right\rangle = 0 \qquad A_{\phi} = i \left\langle u_{\boldsymbol{k}}^{-} \middle| \partial_{\phi} \middle| u_{\boldsymbol{k}}^{-} \right\rangle = \sin^{2} \left(\theta/2 \right)$$

Berry curvature: (gauge independent)
$$\mathcal{F}_{\theta\phi} = \partial_{\theta}A_{\phi} - \partial_{\phi}A_{\theta} = \frac{\sin \theta}{2}$$

If d(k) depends on parameters k: $\mathcal{F}_{k_i,k_j} = \frac{\sin\theta}{2} \frac{\partial(\theta,\phi)}{\partial(k_i,k_j)}$ \checkmark Jacobian matrix

Simple example: d(k) = k

$$\mathcal{F} = \frac{1}{2} \frac{\hat{\mathbf{k}}}{k^2} \quad \text{(monopole field)} \qquad \qquad \gamma_C = \int_S \mathcal{F}_{\theta\phi} \, d\theta d\phi = \frac{1}{2} \left(\begin{array}{c} \text{solid angle} \\ \text{swept out by } \hat{\mathbf{d}}(\mathbf{k}) \end{array} \right)$$

 $2\gamma_C = \frac{\text{solid angle}}{\text{swept out by }} \hat{d}(k)$

Polyacetylene (Su-Schrieffer-Heeger model)



Polyacetylene (Su-Schrieffer-Heeger model)



Provided $d_z = 0$ (required by sublattice symmetry) states with $\delta t > 0$ and $\delta t < 0$ are topologically distinct

Domain Wall States in Polyacetylene



Bulk-boundary correspondence: $\Delta \nu = |\nu_{\rm R} - \nu_{\rm L}| = \# \text{ zero modes}$ (topological invariant characterizing domain wall)

The Integer Quantum Hall State

Integer Quantum Hall State:

[von Klitzing '80]

First example of 2D topological material



The Integer Quantum Hall State

What causes the precise quantization in IQHE?

Explanation One: Edge state transport

IQHE has an energy gap in the bulk:



- charge cannot flow in bulk; only along 1D channels at edges (chiral edge states) $\frac{-\sigma}{2}$
- chiral edge state cannot be localized by disorder (no backscattering)
- edge states are perfect charge conductor!

Explanation Two: Topological band theory

Distinction between the integer quantum Hall state and a conventional insulator $H = -iv(\sigma_{a} + \sigma_{b}) + m(v)\sigma_{z}$ is a topological property of the band structure **[Thouless et al, 84]**

$$\begin{array}{cccc} \mathcal{H}(\mathbf{k}): & \text{Brillouin zone} & & & \text{Hamiltonians with energy gap} \\ \text{Classified by Chern number:} & n = \frac{i}{2\pi} \sum_{\substack{\text{filled} \\ \text{states}}} \int \mathcal{F} d^2 k & (= \text{topological invariant}) & n \in \mathbb{Z} \\ \\ \hline & & \text{Kubo formula:} & \sigma_{xy} = \frac{e^2}{h} \frac{i}{2\pi} \sum_{\substack{\text{filled} \\ \text{states}}} \int \mathcal{F} d^2 k \end{array}$$

does not change under smooth deformations, as long as bulk energy gap is not closed

Bulk-boundary correspondence

topological invariant

$$n = \frac{i}{2\pi} \sum_{\substack{\text{filled}\\\text{states}}} \int \mathcal{F} d^2 k$$

 $n \in \mathbb{Z}$

Zero-energy state at interface



Bulk-boundary correspondence:

Zero-energy states must exist at the interface between two different topological phases

Follows from the quantization of the topological invariant.

 $\Delta n = |n_{
m L} - n_{
m R}|\;$ = number or edge modes

Stable gapless edge states:

- robust to smooth deformations (respect symmetries of the system)
- insensitive to disorder, impossible to localize
- cannot exist in a purely 1D system (Fermion doubling theorem)

IQHE: chiral Dirac Fermion



Chern insulator on square lattice

Chern insulator = "integer quantum Hall state on a lattice" (similar to Haldane honeycomb model [D. Haldane PRL '88])

[Bernevig, Hughes, Zhang]

(two orbital model: s and p. Inter-orbital coupling + intra-orbital dispersion)

Chern insulator on square lattice: $\mathcal{H}_{CI} = \mathbf{d}(\mathbf{k}) \cdot \vec{\sigma} + \epsilon_0(\mathbf{k})\sigma_0$ (breaks time-reversal symmetry)

$$\begin{aligned} d_{x}(\mathbf{k}) &= \sin k_{x} \quad d_{y}(\mathbf{k}) = \sin k_{y} \quad d_{z}(\mathbf{k}) = (2 + M - \cos k_{x} - \cos k_{y}) \\ E_{\pm} &= \pm |\mathbf{d}(\mathbf{k})| \quad \text{Spectrum flattening:} \quad \hat{\mathbf{d}}(\mathbf{k}) = \frac{\mathbf{d}(\mathbf{k})}{|\mathbf{d}(\mathbf{k})|} \\ & \underset{M > 0 \text{ and} \\ M < -4 \\ n = 0 \quad d_{y} \quad d_{x} \quad d_{x}$$

Chern insulator on square lattice

Chern insulator on square lattice:
$$\mathcal{H}_{CI} = \mathbf{d}(\mathbf{k}) \cdot \vec{\sigma} + \epsilon_0(\mathbf{k})\sigma_0$$

$$d_x(\mathbf{k}) = \sin k_x \qquad d_y(\mathbf{k}) = \sin k_y \qquad d_z(\mathbf{k}) = (2 + M - \cos k_x - \cos k_y)$$

Effective low-energy continuum theory for M=0: (expand around $\mathbf{k} = 0$; σ_0 term can be neglected)

$$H_{\rm CI} = k_x \sigma_x + k_y \sigma_y + M \sigma_z$$

two eigenfunctions with energies: $E_{\pm} = \pm \lambda = \pm \sqrt{\mathbf{k}^2 + M^2}$

$$\left|u_{\mathbf{k}}^{+}\right\rangle = \frac{1}{\sqrt{2\lambda(\lambda - M)}} \begin{pmatrix}k_{x} - ik_{y}\\\lambda - M\end{pmatrix} \qquad \left|u_{\mathbf{k}}^{-}\right\rangle = \frac{1}{\sqrt{2\lambda(\lambda + M)}} \begin{pmatrix}-k_{x} + ik_{y}\\\lambda + M\end{pmatrix}$$

Berry curvature: $F_{xy} = \partial_{k_x} A_{k_y} - \partial_{k_y} A_{k_x} = +\frac{M}{2\lambda^3}$

gives nonzero Chern number
$$n = \frac{1}{2\pi} \int d^2 k F_{xy} = \frac{1}{2} \operatorname{sgn}(M)$$
 (= Hall conductance σ_{xy})

NB: Chern number must be integer for integrals over compact manifolds.

Proper regularization of Dirac Hamiltonian will lead to $n \in \mathbb{Z}$

zero-energy state at boundary



Chiral edge state at boundary between two Chern insulators with different n $\psi_0 = -$

$$\frac{1}{\sqrt{2}} \begin{pmatrix} 1\\ -1 \end{pmatrix} e^{ik_y y} e^{-\int_0^x M(x') dx'}$$